## NSN 5961-00-594-1885

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View Online at https://aerobasegroup.com/nsn/5961-00-594-1885 **Inclosure Material:** Metal **Overall Length:** 1.573 inches **Overall Height:** 0.328 inches **Overall Width:** 1.050 inches **Mounting Facility Quantity: Internal Configuration:** Junction contact Joint Electronic Device Engineering Council/jedec/case Outline Designation: To-3 **Electrode Internally-electrically Connected To Case:** Collector **Mounting Method:** Unthreaded hole **Features Provided:** Hermetically sealed case **Semiconductor Material:** Silicon Voltage Rating In Volts Per Characteristic: 600.0 collector to emitter voltage/static/base open **Current Rating Per Characteristic:** 20.00 amperes source cutoff current and 5.00 amperes source cutoff current **Power Rating Per Characteristic:** 100.0 watts small-signal input power, common-collector preset **Transfer Ratio:** 8.0 static forward current transfer ratio, common-emitter **Maximum Operating Tempurature Per Measurement Point:** 150.0 degrees celsius junction **Special Features:** Junction pattern arrangement: npn **Terminal Type And Quantity:** 2 pin and 1 case Shelf Life: N/a **Unit Of Measure:** 

**Demilitarization:** 

No

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